Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:
Metal	
Overall L	ength:
0.188 inch	nes
Terminal	Length:
0.500 inch	nes
Overall D	iameter:
0.220 inch	nes
Mounting	Method:
Terminal	
Terminal	Circle Diameter:
0.100 inch	nes
Features	Provided:
Hermetica	Ily sealed case
Semicono	ductor Material:
Silicon	
Voltage R	ating In Volts Per Characteristic:
85.0 peak	k-point voltage
Current R	ating Per Characteristic:
15.00 milli	amperes forward current, average
Terminal	Type And Quantity:
3 uninsula	ted wire lead
Specifica	tion Data:
80131-rele	ease4592 professional/industrial association specification
Shelf Life	:
N/a	
Unit Of M	easure:
Demilitari	ization:
No	
Fiig:	
A110a0	